Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (L^2 - π -MOSV)

2SJ512

Chopper Regulator, DC-DC Converter and Motor Drive **Applications**

• Low drain-source ON resistance : R_{DS} (ON) = 1.0Ω (typ.)

High forward transfer admittance $|Y_{fs}| = 3.7 \text{ S (typ.)}$

• Low leakage current : $IDSS = -100 \mu A (max) (VDS = -250 V)$

Enhancement-mode : $V_{th} = -1.5 \sim -3.5 \text{ V (V}_{DS} = -10 \text{ V, I}_{D} = -1 \text{ mA)}$

Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-250	V	
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	-250	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC (Note 1)	I _D	-5	Α	
	Pulse (Note 1)	I_{DP}	-20	Α	
Drain power dissipation	n (Tc = 25°C)	P_{D}	30	W	
Single pulse avalanche	e energy (Note 2)	E _{AS}	155	mJ	
Avalanche current		I _{AR}	-5	Α	
Repetitive avalenche e	nergy (Note 3)	E _{AR}	3.0	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature ra	ange	T _{stg}	-55~150	°C	

1. GATE 2. DRAIN 3. SOURCE **JEDEC** JEITA SC-67

2-10R1B

Weight: 1.9 g (typ.)

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Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	4.16	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: V_{DD} = -50 V, T_{ch} = 25°C (initial), L = 10.5 mH, R_G = 25 Ω , I_{AR} = -5 A

Note 3: Repetitive rating; Pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device.

Please handle with caution.

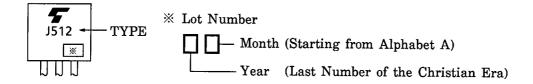
Electrical Characteristics (Ta = 25°C)

Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cut-off cur	rent	I _{DSS}	V _{DS} = -250 V, V _{GS} = 0 V	_	_	-100	μΑ
Drain-source brovoltage	eakdown	V _{(BR)DSS}	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-250	_	_	V
Gate threshold v	oltage	V_{th}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.5	_	-3.5	V
Drain-source Of	N resistance	R _{DS (ON)}	$V_{GS} = -10 \text{ V}, I_D = -2.5 \text{ A}$	_	1.0	1.25	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = -10 V, I _D = -2.5 A	1.8	3.7	_	S
Input capacitanc	е	C _{iss}		_	800	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	80	_	pF
Output capacitance		C _{oss}	1		250	_	
Switching time	Rise time	t _r	V_{GS}^{OV} $I_{D} = -2.5A$ V_{OUT} $R_{L} = 40\Omega$ $V_{DD} = -100V$	_	16	_	- ns
	Turn-on time	t _{on}		_	35	_	
	Fall time	t _f		_	9	_	
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\mathbf{W}} = 10 \mu \text{s}$	_	70	_	
Total gate charge (Gate-source plus gate-drain)		Q_{g}	V _{DD} ≈ -200 V, V _{GS} = -10 V,	_	22	_	nC
Gate-source charge		Q_{gs}	I _D = -5 A	_	14	_	
Gate-drain ("miller") charge		Q_{gd}			8	_	

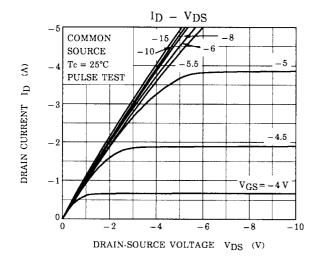
Source-Drain Ratings and Characteristics (Ta = 25°C)

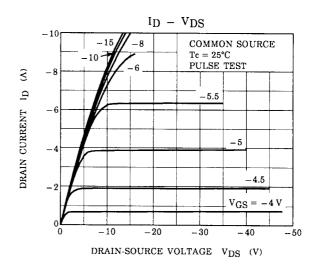
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	-	1	_	-5	Α
Pulse drain reverse current (Note 1)	I _{DRP}	-	_	_	-20	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = -5 A, V _{GS} = 0 V	_	_	2.0	V
Reverse recovery time	t _{rr}	I _{DR} = -5 A, V _{GS} = 0 V		205	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} / dt = 100 A / μs		2.1	_	μC

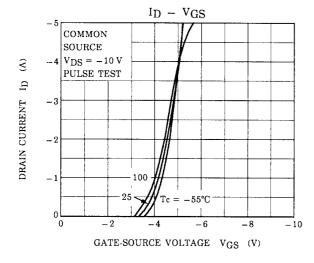
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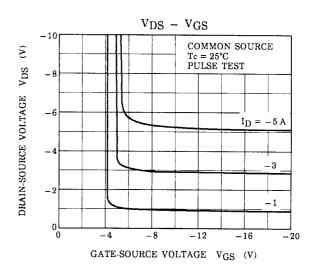


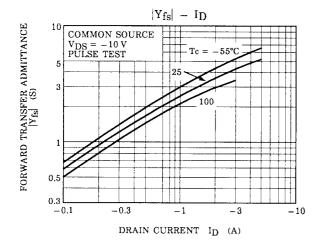
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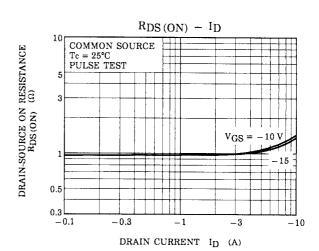




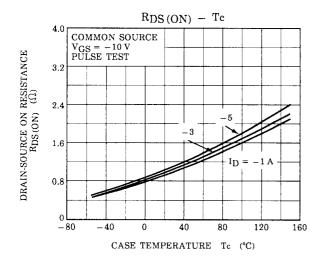


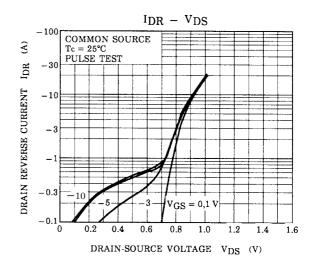


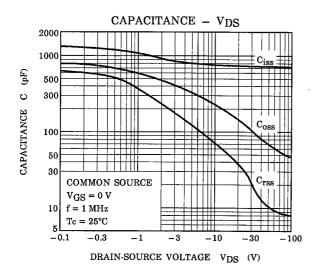


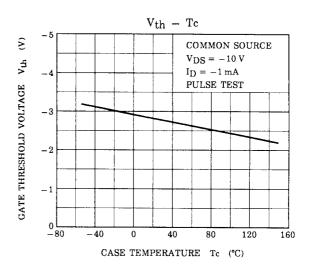


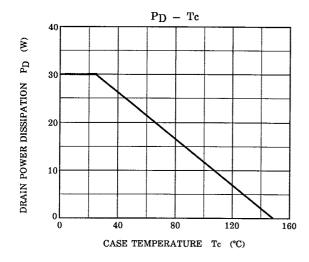
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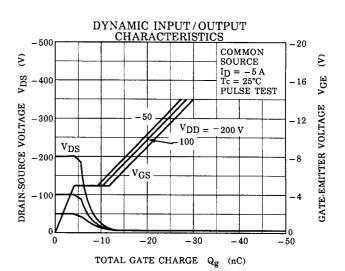




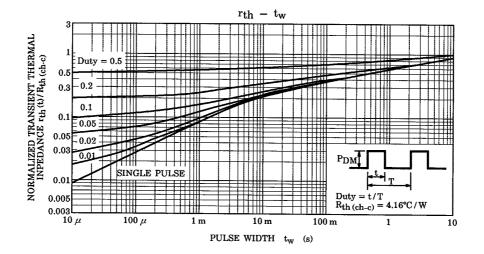


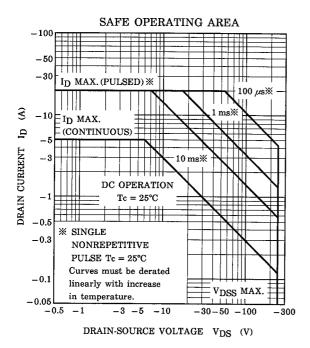


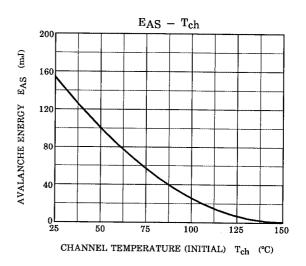


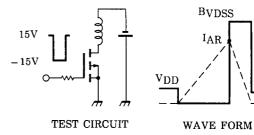


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$$\begin{array}{ll} R_G = 25\Omega \\ V_{DD} = -50V, \; L = 10.5 mH \end{array} \quad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot (\frac{B_{VDSS}}{B_{VDSS} - V_{DD}}) \end{array}$$

 $v_{\rm DS}$

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